

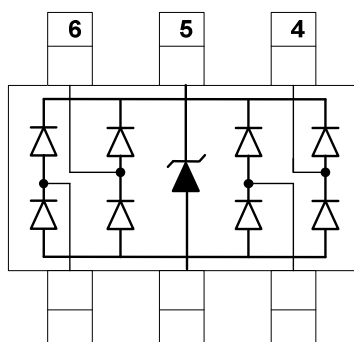
Description

The DL3304S2 is an ultra low capacitance TVS array, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The DL3304S2 has an ultra-low capacitance with a typical value at 0.3pF (I/O to I/O) , and complies with the IEC 61000-4-2 (ESD) standard with ±25kV air and ±20kV contact discharge. It is assembled into a 6-pin lead-free SOT23-6 package. The low capacitance array make it ideal for four high speed data and transmission line. This device is optimized for ESD protection of portable electronics.

Mechanical Characteristics

- ◆ Package: SOT23-6
- ◆ Lead Finish: Matte Tin
- ◆ Case Material: “Green” Molding Compound
- ◆ Moisture Sensitivity: Level 3 per J-STD-020
- ◆ Terminal Connections: See Diagram Below
- ◆ Marking Information: See Below

Dimensions and Pin Configuration



Circuit and Pin Schematic

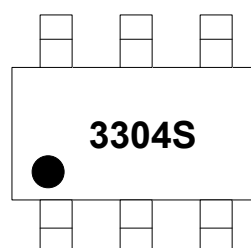
Features

- ◆ Ultra low capacitance: 0.3pF typical (I/O to I/O)
- ◆ Ultra low leakage: nA level
- ◆ Ultra low operating voltage: 3.3V
- ◆ Low clamping voltage
- ◆ Up to 4 data lines and one power line protects
- ◆ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
Air discharge: ±25kV Contact discharge: ±20kV
 - IEC61000-4-5 (Lightning) : 5A(8/20µs)
- ◆ ROHS Compliant

Applications

- ◆ LAN Applications
- ◆ Fingerprint
- ◆ Video Lines Protection
- ◆ Handheld Electronics
- ◆ 3.3V Operating Systems
- ◆ Analog Input Lines Protection
- ◆ Data and I/O Lines Protection

Marking Information



3304S = Device Marking Code
Dot denotes Pin1

Ordering Information

Part Number	Marking	Packaging	Reel Size
DL3304S2	3304S	3000/Tape & Reel	7 inch

Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

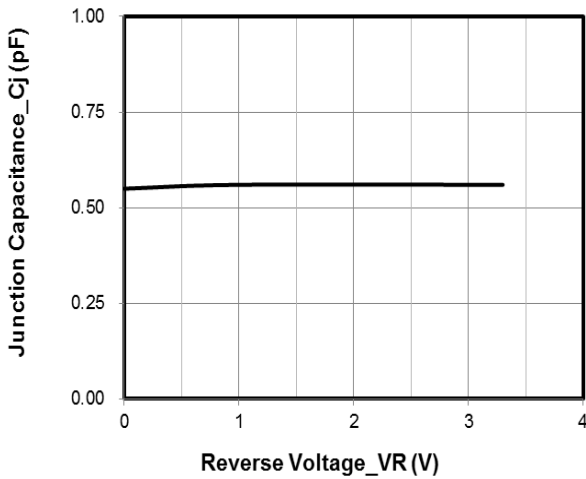
Parameter	Symbol	Value	Unit
Peak Pulse Power (tp=8/20μs)	PPP	100	W
Peak Pulse Current (tp=8/20μs)	I _{PP}	5	A
ESD per IEC 61000-4-2 (Air)	V _{ESD}	±25	kV
ESD per IEC 61000-4-2 (Contact)		±20	
Operating Temperature Range	T _J	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

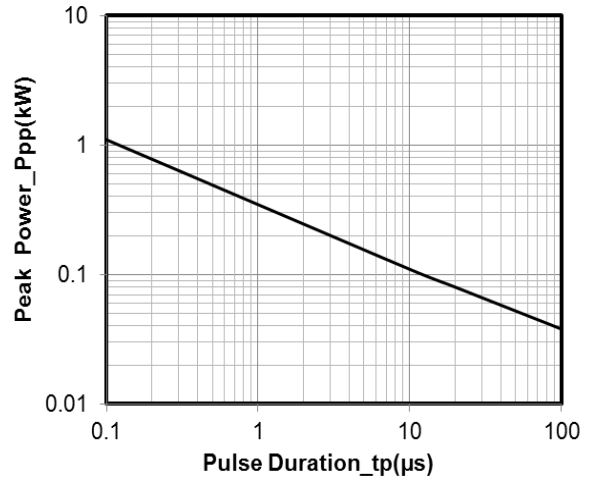
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			3.3	V	Any I/O pin to ground
Breakdown Voltage	V _{PT}	3.5			V	I _T = 2μA, any I/O pin to ground
Snap-Back Voltage	V _{SB}	2.8			V	I _T = 50mA, any I/O pin to ground
Reverse Leakage Current	I _R			0.2	μA	V _{RWM} = 3.3V, any I/O pin to ground
Clamping Voltage	V _C			10	V	I _{PP} = 1A (8 x 20μs pulse), any I/O pin to ground
Clamping Voltage	V _C			20	V	I _{PP} = 5A (8 x 20μs pulse), any I/O pin to ground
Junction Capacitance	C _J		0.3	0.4	pF	V _R = 0V, f = 1MHz, between I/O pins
Junction Capacitance	C _J		0.6	0.8	pF	V _R = 0V, f = 1MHz, any I/O pin to ground

Note 1: I/O pins are Pin 1, 3, 4 and 6

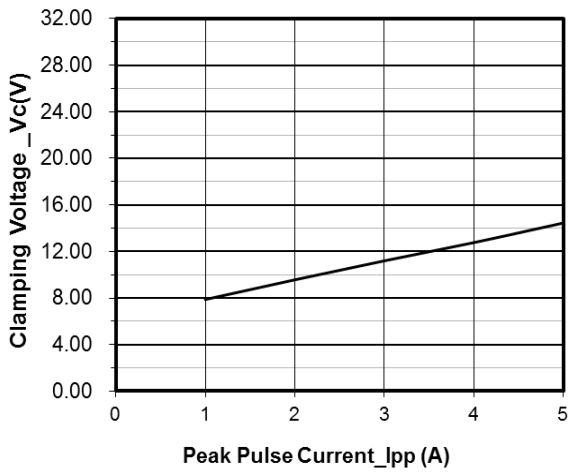
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



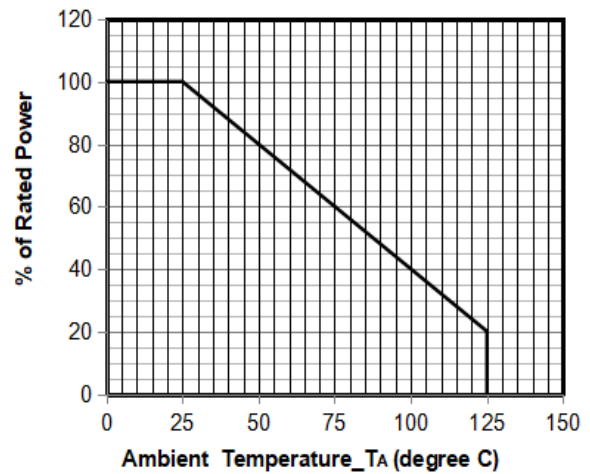
Junction Capacitance vs. Reverse Voltage



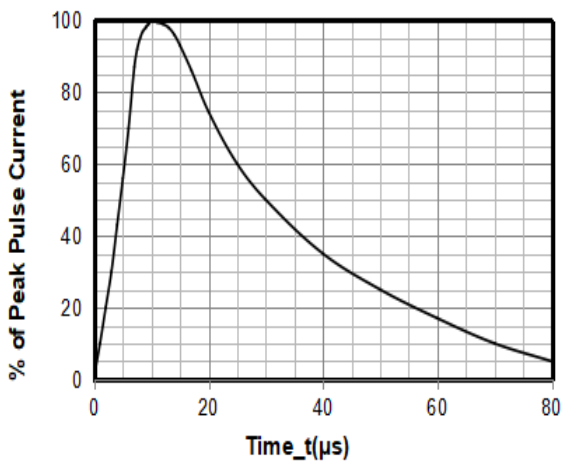
Peak Pulse Power vs. Pulse Time



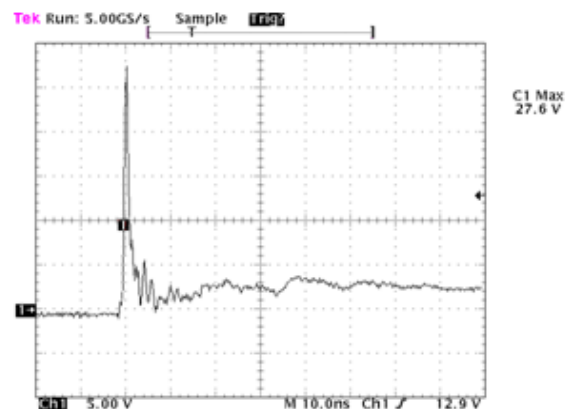
Clamping Voltage vs. Peak Pulse Current



Power Derating Curve



8 X 20μs Pulse Waveform



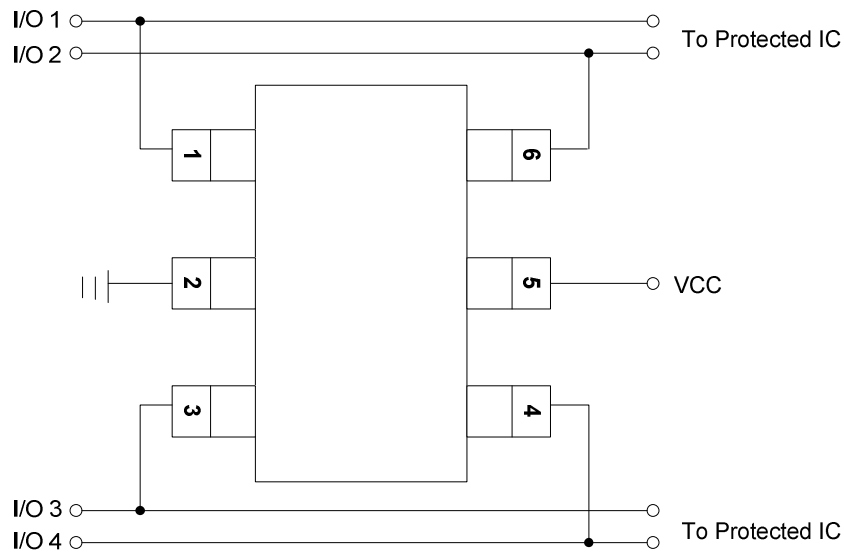
Note: Data is taken with a 10x attenuator

ESD Clamping Voltage

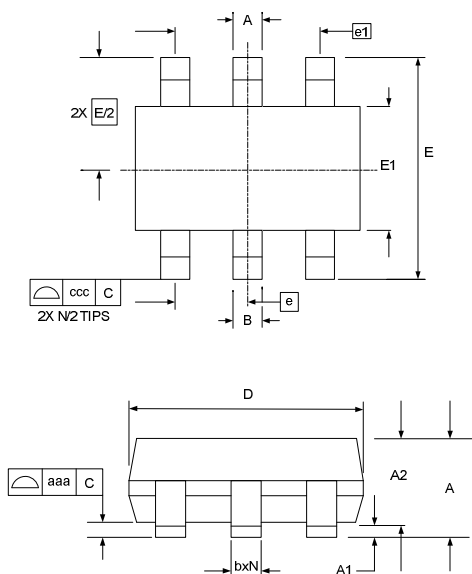
8 kV Contact per IEC61000-4-2

Typical Application

The DL3304S2 is designed to protect four data lines from transient over-voltages by clamping them to fixed reference. When the voltage on the protected line exceeds the reference voltage (plus diode VF) the steering diodes are forward biased, conducting the transient current away from the sensitive circuitry. Data lines are connected at pins 1, 3, 4 and 6. The negative reference (REF1) is connected at pin 2. This pin should be connected directly to a ground plane on the board for best results. The path length is kept as short as possible to minimize parasitic inductance. The positive reference (REF2) is connected at pin 5.

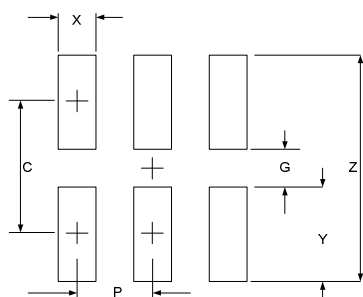


SOT23-6 Package Outline Drawing



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.90		1.45	0.035		0.057
A1	0.00		0.15	0.000		0.006
A2	0.90	1.15	1.30	0.035	0.045	0.051
B	0.25		0.50	0.010		0.020
C	0.08		0.22	0.003		0.009
D	2.80	2.90	3.10	0.110	0.114	0.122
E1	1.50	1.60	1.75	0.060	0.063	0.069
E	2.80 BSC			0.110 BSC		
e	0.95 BSC			0.037 BSC		
e1	1.90 BSC			0.075 BSC		
N	6			6		
aaa	0.10			0.004		
ccc	0.20			0.008		

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
C	2.50	0.098
G	1.40	0.055
P	0.95	0.037
X	0.60	0.024
Y	1.10	0.043
Z	3.60	0.141

Contact Information

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